

MOS FIELD EFFECT TRANSISTOR μ PA1728

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The μ PA1728 is N-Channel MOS Field Effect Transistor designed for high current switching applications.

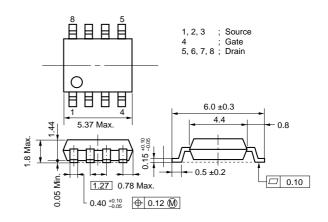
FEATURES

- Single chip type
- Low On-state Resistance
- ★ $R_{DS(on)1} = 19 \text{ m}\Omega \text{ (TYP.)} (V_{GS} = 10 \text{ V}, \text{ ID} = 4.5 \text{ A})$
- ★ $R_{DS(on)2} = 23 \text{ m}\Omega \text{ (TYP.)} \text{ (Vgs} = 4.5 \text{ V}, \text{ ID} = 4.5 \text{ A} \text{)}$
- ★ RDS(on)3 = 24 m Ω (TYP.) (VGS = 4.0 V, ID = 4.5 A)
- ★ Low Ciss : Ciss = 1700 pF (TYP.)
 - Built-in G-S protection diode
 - Small and surface mount package (Power SOP8)

ORDERING INFORMATION

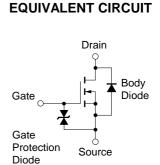
PART NUMBER	PACKAGE
μPA1728	Power SOP8

PACKAGE DRAWING (Unit : mm)



ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, All terminals are connected.)

Drain to Source Voltage (Vgs = 0 V)	VDSS	60	V
Gate to Source Voltage (VDS = 0 V)	Vgss	±20	V
Drain Current (DC)	D(DC)	±9	А
Drain Current (Pulse) Note1	D(pulse)	±36	А
Total Power Dissipation (T _A = 25 °C) Note2	Р⊤	2.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to + 150	°C
Single Avalanche Current Note3	las	9	А
Single Avalanche Energy Note3	Eas	8.1	mJ
Notes 1. PW \leq 10 μ s, Duty cycle \leq 1 %			



- 2. Mounted on ceramic substrate of 1200 mm² x 2.2 mm
 - **3.** Starting T_{ch} = 25°C, R_G = 25 Ω , T_{GS} = 20 V \rightarrow 0 V

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Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage Exceeding the rated voltage may be applied to this device.

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* ELECTRICAL CHARACTERISTICS (TA = 25 °C, All terminals are connected.)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, Id = 4.5 A		19	26	mΩ
	RDS(on)2	Vgs = 4.5 V, Id = 4.5 A		23	29	mΩ
	RDS(on)3	Vgs = 4.0 V, Id = 4.5 A		24	34	mΩ
Gate to Source Cut-off Voltage	VGS(off)	$V_{DS} = 10 V, I_{D} = 1 mA$	1.5	2.0	2.5	V
Forward Transfer Admittance	yfs	Vbs = 10 V, lb = 4.5 A	6.0	12		S
Drain Leakage Current	IDSS	$V_{DS} = 60 V, V_{GS} = 0 V$			10	μA
Gate to Source Leakage Current	lgss	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μA
Input Capacitance	Ciss	V _{DS} = 10 V		1700		pF
Output Capacitance	Coss	Vgs = 0 V		270		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		130		pF
Turn-on Delay Time	td(on)	ID = 4.5 A		17		ns
Rise Time	tr	$V_{GS(on)} = 10 V$		69		ns
Turn-off Delay Time	td(off)	Vdd = 30 V		77		ns
Fall Time	tr	Rg = 10 Ω		31		ns
Total Gate Charge	QG	ID = 9 A		31		nC
Gate to Source Charge	QGS	V _{DD} = 48 V		4.4		nC
Gate to Drain Charge	Qgd	Vgs = 10 V		9.1		nC
Body Diode Forward Voltage	VF(S-D)	IF = 9 A, VGS = 0 V		0.82		V
Reverse Recovery Time	trr	IF = 9 A, VGS = 0 V		41		ns
Reverse Recovery Charge	Qrr	di/dt = 100A/µs		76		nC

TEST CIRCUIT 2 SWITCHING TIME

D.U.T.

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. Duty Cycle ≤ 1 %

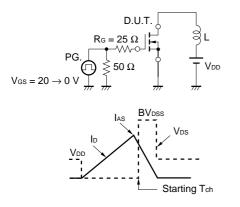
 $\tau = 1 \, \mu s$

PG

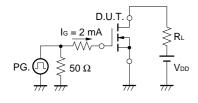
 V_{GS}

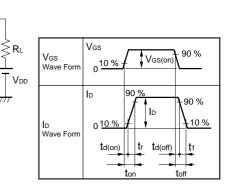
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TEST CIRCUIT 1 AVALANCHE CAPABILITY



TEST CIRCUIT 3 GATE CHARGE





[MEMO]

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